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|-----------------------------------|---------------------------------------|--|---|-------------|
| <b>Notice of References Cited</b> | Application/Control No.<br>10/502,465 |  | Applicant(s)/Patent Under<br>Reexamination<br>NASSIOPOULOU ET AL. |             |
|                                   | Examiner<br>Frederick F. Rosenberger  |  | Art Unit<br>2884  | Page 1 of 1 |

#### U.S. PATENT DOCUMENTS

| * |   | Document Number<br>Country Code-Number-Kind Code | Date<br>MM-YYYY | Name           | Classification |
|---|---|--|-----------------|----------------|----------------|
| * | A | US-6,832,523                                     | 12-2004         | Benzel et al.  | 73/763         |
| * | B | US-6,759,265                                     | 07-2004         | Artmann et al. | 438/53         |
|   | C | US-  |                 |                |                |
|   | D | US-  |                 |                |                |
|   | E | US-  |                 |                |                |
|   | F | US-  |                 |                |                |
|   | G | US-  |                 |                |                |
|   | H | US-  |                 |                |                |
|   | I | US-  |                 |                |                |
|   | J | US-  |                 |                |                |
|   | K | US-  |                 |                |                |
|   | L | US-  |                 |                |                |
|   | M | US-  |                 |                |                |

#### FOREIGN PATENT DOCUMENTS

| * |   | Document Number<br>Country Code-Number-Kind Code | Date<br>MM-YYYY | Country | Name | Classification |
|---|---|--|-----------------|---------|------|----------------|
|   | N |  |                 |         |      |                |
|   | O |  |                 |         |      |                |
|   | P |  |                 |         |      |                |
|   | Q |  |                 |         |      |                |
|   | R |  |                 |         |      |                |
|   | S |  |                 |         |      |                |
|   | T |  |                 |         |      |                |

#### NON-PATENT DOCUMENTS

| * |   | Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)  |
|---|---|--|
|   | U | Nassiopoulos, A.G. "Local Formation and Patterning of Porous Silicon." in: Canham, L., Properties of Porous Silicon (England, Short Run Press, 1997), pp. 77-80. |
|   | V | Halimaoui, A. "Porous Silicon Formation by Anodisation." in: Canham, L., Properties of Porous Silicon (England, Short Run Press, 1997), pp. 12-14.               |
|   | W |  |
|   | X |  |

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